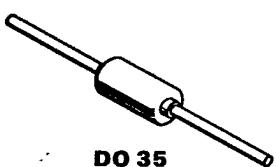


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DO 35

D0201YR DIAC

The D0201 bidirectional trigger diode is a low cost PNPN element suitable for triggering TRIAC's. These parts are fabricated using TAG's high performance glassivated process and are intended for high volume applications.

Absolute Maximum Ratings TA = 25 °C unless otherwise noted

Parameter	Part Nr.	Symbol	Min.	Nom.	Max.	Unit	Test Conditions
Break-Over Voltage	D0201YR	V _{BO}	29	32	35	V	
Peak Current		I _P		2	A	10 µs pulse, 120 Hz repetition	Figure 2
Operating Temperature		T _j	-40		125	°C	
Storage Temperature		T _{stg}	-40		125	°C	
Soldering Temperature		T _{sld}		250	°C	1.6 mm from case, 10 s max.	

Electrical Characteristics TA = 25 °C unless otherwise noted

Parameter	Symbol	Min.	Max.	Unit	Test Conditions
Break-Over Voltage Symmetry	ΔV _{BO}		3	V	
Break-Over Current	I _{BO}		50	µA	C _T = 27 nF see Figure 3
Peak Output Voltage	V _p	5		V	C _T = 0.1 µF see Figure 3

Figure 1

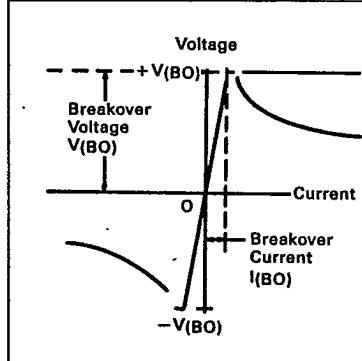


Figure 2

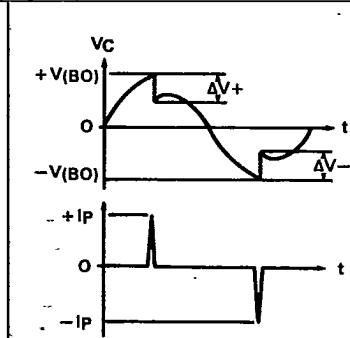
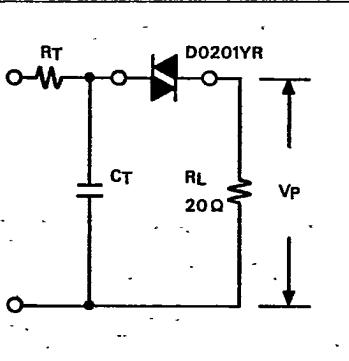


Figure 3



D02